NPN Epitaxial Silicon Transistor

KSD1616A

Features

- Audio Frequency Power Amplifier and Medium Speed Switching
- Complement to KSB1116/KSB1116A
- These are Pb–Free Devices

ABSOLUTE MAXIMUM RATINGS

(Values are at $T_A = 25^{\circ}C$ unless otherwise noted.)

| Symbol | Parameter | Value | Unit |
|------------------|------------------------------------|------------|------|
| V _{CBO} | Collector-Base Voltage | 120 | V |
| V _{CEO} | Collector-Emitter Voltage | 60 | V |
| V _{EBO} | Emitter-Base Voltage | 6 | V |
| ۱ _C | Collector Current (DC) | 1 | А |
| I _{CP} | Collector Current (Pulse) (Note 1) | 2 | А |
| TJ | Junction Temperature | 150 | °C |
| T _{STG} | Storage Temperature | –55 to 150 | °C |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Pulse width \leq 10 ms, duty cycle < 50%.

THERMAL CHARACTERISTICS

(Values are at $T_A = 25^{\circ}C$ unless otherwise noted.)

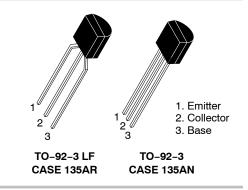
| Symbol | Parameter | Мах | Unit |
|---------------|--|------|-------|
| PD | Total Device Dissipation | 0.75 | W |
| | Derate Above 25°C | 6 | mW/∘C |
| $R_{	hetaJA}$ | Thermal Resistance, Junction-to-Ambient | 160 | °C/W |

2. PCB size: FR-4, 76 mm \times 114 mm \times 1.57 mm (3.0 inch \times 4.5 inch \times 0.062 inch) with minimum land pattern size.

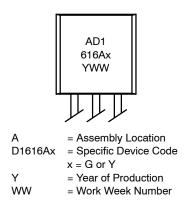


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MARKING DIAGRAM



ORDERING INFORMATION

| Device | Package | Shipping |
|-------------|-------------------------|----------------------------|
| KSD1616AGBU | TO-92-3 (Pb-Free) | 10,000 Units / Bulk Bag |
| KSD1616AGTA | TO-92-3 LF (Pb-Free) | 2,000 Units / Fan-Fold |
| KSD1616AYTA | TO-92-3 LF (Pb-Free) | 2,000 Units / Fan-Fold |

ELECTRICAL CHARACTERISTICS

(Values are at $T_A = 25^{\circ}C$ unless otherwise noted.)

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|----------------------|--|---|-----|------|------|------|
| BV _{CBO} | Collector-Base Breakdown Voltage | I _C = 100 μA, I _E = 0 | 120 | - | - | V |
| BV _{CEO} | Collector-Emitter Breakdown Voltage | I _C = 1 mA, I _B = 0 | 60 | - | - | V |
| BV_{EBO} | Emitter-Base Breakdown Voltage | I _E = 100 μA, I _C = 0 | 6 | - | - | V |
| I _{CBO} | Collector Cut-Off Current | $V_{CB} = 60 \text{ V}, \text{ I}_{E} = 0$ | - | - | 100 | nA |
| I _{EBO} | Emitter Cut-Off Current | $V_{EB} = 6 V, I_{C} = 0$ | - | - | 100 | nA |
| h _{FE1} | DC Current Gain | V_{CE} = 2 V, I_{C} = 100 mA | 135 | - | 400 | |
| h _{FE2} | DC Current Gain | $V_{CE} = 2 V, I_{C} = 1 A$ | 81 | - | - | |
| V _{BE(on)} | Base-Emitter On Voltage (Note 3) | V_{CE} = 2 V, I_{C} = 50 mA | 600 | 640 | 700 | mV |
| V _{CE(sat)} | Collector-Emitter Saturation Voltage (Note 3) | I _C = 1 A, I _B = 50 mA | - | 0.15 | 0.30 | V |
| V _{BE(sat)} | Base–Emitter Saturation Voltage (Note 3) | I _C = 1 A, I _B = 50 mA | - | 0.9 | 1.2 | V |
| C _{ob} | Output Capacitance | V _{CE} = 10 V, I _E = 0, f = 1 MHz | - | 19 | - | pF |
| f _T | Current Gain Bandwidth Product | V_{CE} = 2 V, I_{C} = 100 mA | 100 | 160 | - | MHz |
| t _{ON} | Turn-On Time | $V_{CC} = 10 \text{ V}, \text{ I}_{C} = 100 \text{ mA},$ | - | 0.07 | - | μs |
| t _{STG} | Storage Time | $I_{B1} = -I_{B2} = 10 \text{ mA},$ $V_{BE(off)} = -2 \text{ V} \sim -3 \text{ V}$ | - | 0.95 | - | μs |
| t _F | Fall Time | | - | 0.07 | - | μs |

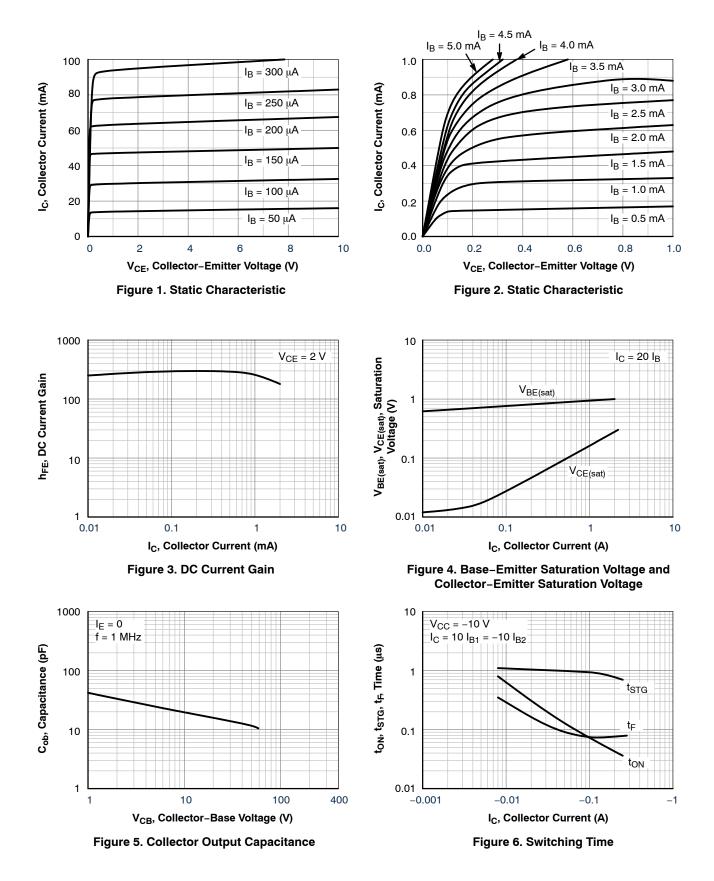
Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions. 3. Pulse test: pulse width < 350 μ s, duty cycle \leq 2% pulsed.

h_{FE} CLASSIFICATION

| Classification | Y | G | |
|----------------|-----------|-----------|--|
| hFE1 | 135 ~ 270 | 200 ~ 400 | |

KSD1616A

TYPICAL PERFORMANCE CHARACTERISTICS



KSD1616A

TYPICAL CHARACTERISTICS (continued)

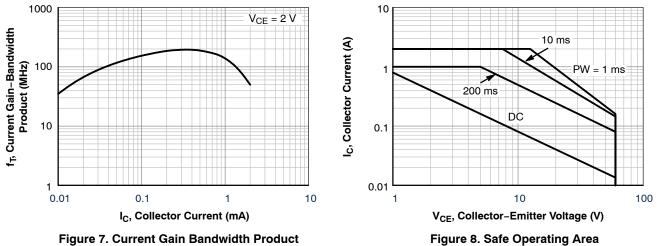


Figure 7. Current Gain Bandwidth Product

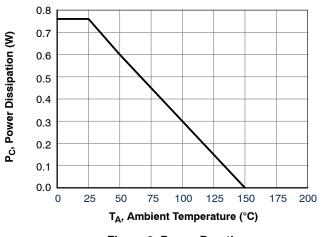
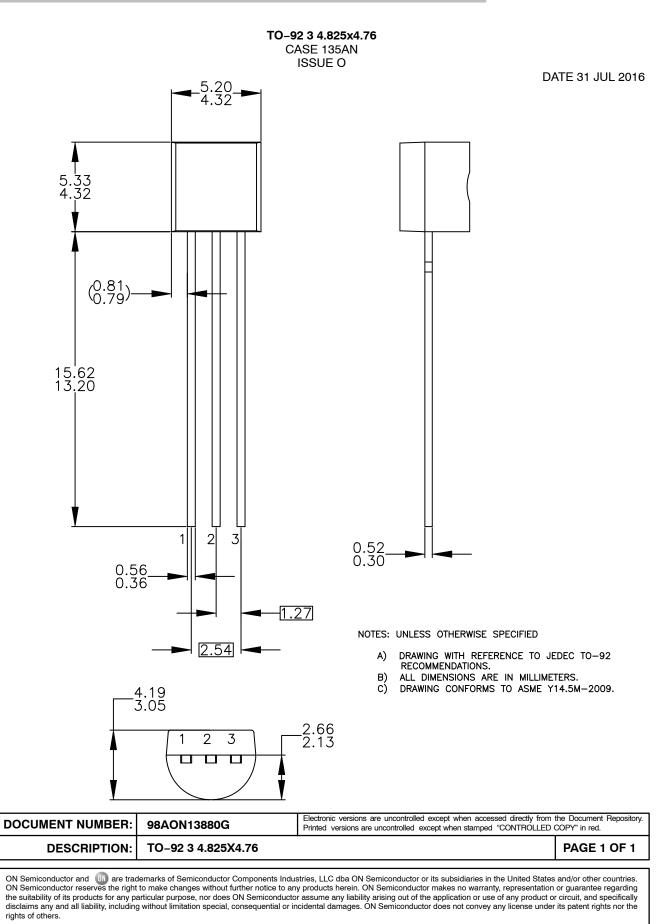


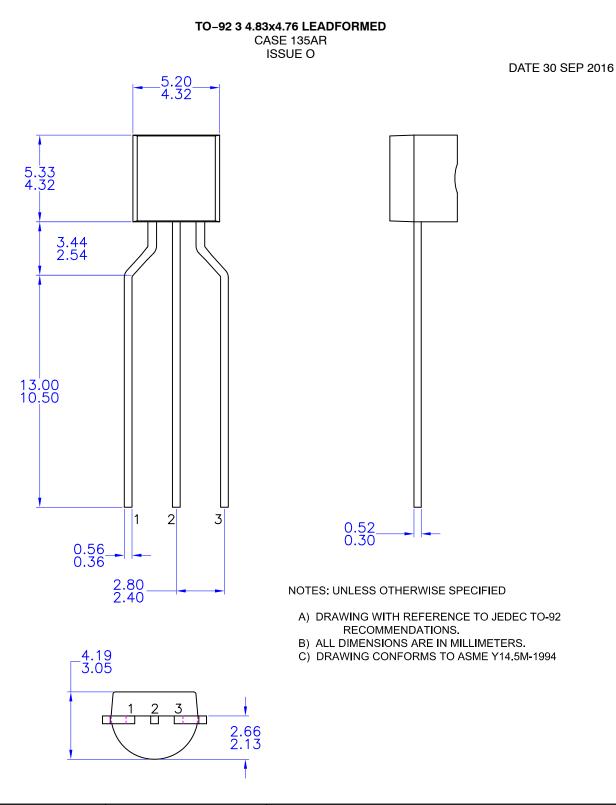
Figure 9. Power Derating





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